CPH3455

ON Semiconductor®

N-Channel Power MOSFET 35V, 3A, 104mΩ, Single CPH3

http://onsemi.com

Features

- ON-resistance RDS(on)1=80m Ω (typ.)
- · 4V drive
- · Halogen free compliance

Specifications

Absolute Maximum Ratings at Ta=25°C

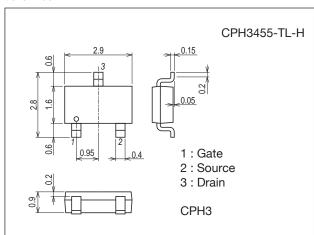
Parameter	Symbol	Conditions	Ratings	Unit
Drain to Source Voltage	VDSS		35	V
Gate to Source Voltage	VGSS		±20	V
Drain Current (DC)	ID		3	Α
Drain Current (Pulse)	IDP	PW≤10µs, duty cycle≤1%	12	Α
Allowable Power Dissipation	PD	When mounted on ceramic substrate (900mm ² ×0.8mm)	1	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

This product is designed to "ESD immunity < 200V*", so please take care when handling.

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Package Dimensions

unit : mm (typ) 7015A-004



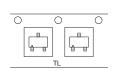
Product & Package Information

• Package : CPH3

• JEITA, JEDEC : SC-59, TO-236, SOT-23

• Minimum Packing Quantity : 3,000 pcs./reel

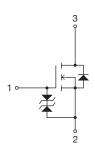
Packing Type: TL



Marking



Electrical Connection

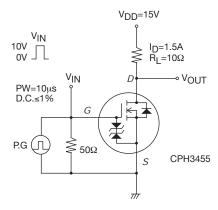


^{*} Machine Model

Electrical Characteristics at Ta=25°C

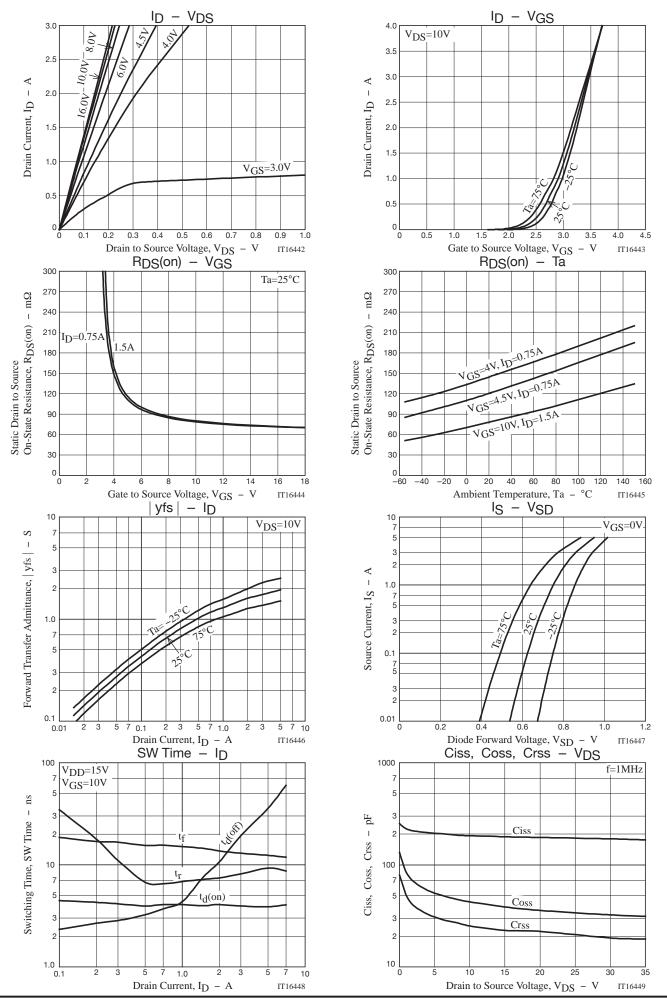
Parameter	Symbol	Conditions	Ratings			Unit
Parameter		Conditions	min	typ	max	Unit
Drain to Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0V	35			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =35V, V _{GS} =0V			1	μΑ
Gate to Source Leakage Current	IGSS	V _{GS} =±16V, V _{DS} =0V			±10	μΑ
Cutoff Voltage	V _{GS} (off)	V _{DS} =10V, I _D =1mA	1.2		2.6	٧
Forward Transfer Admittance	yfs	V _{DS} =10V, I _D =1.5A		1.7		S
Static Drain to Source On-State Resistance	R _{DS} (on)1	I _D =1.5A, V _{GS} =10V		80	104	mΩ
	R _{DS} (on)2	I _D =0.75A, V _G S=4.5V		123	173	mΩ
	R _{DS} (on)3	I _D =0.75A, V _{GS} =4V		148	208	mΩ
Input Capacitance	Ciss			186		рF
Output Capacitance	Coss	V _{DS} =20V, f=1MHz		36		рF
Reverse Transfer Capacitance	Crss			22		рF
Turn-ON Delay Time	t _d (on)			4.2		ns
Rise Time	t _r			4.7		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit.		15		ns
Fall Time	tf			5.7		ns
Total Gate Charge	Qg			4		nC
Gate to Source Charge	Qgs	V _{DS} =20V, V _{GS} =10V, I _D =3A		0.9		nC
Gate to Drain "Miller" Charge	Qgd			0.7		nC
Diode Forward Voltage	V _{SD}	I _S =3A, V _{GS} =0V		0.86	1.2	V

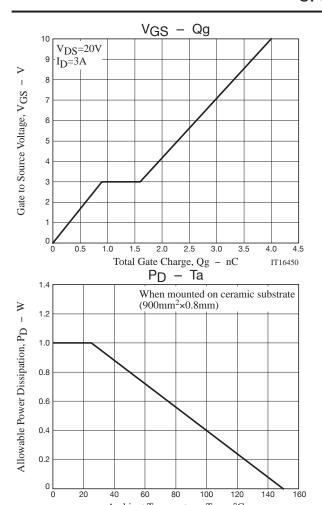
Switching Time Test Circuit



Ordering Information

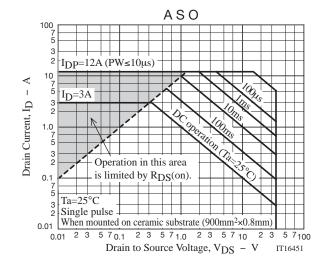
Device	Package	Shipping	memo	
CPH3455-TL-H	CPH3	3,000pcs./reel	Pb-Free and Halogen Free	





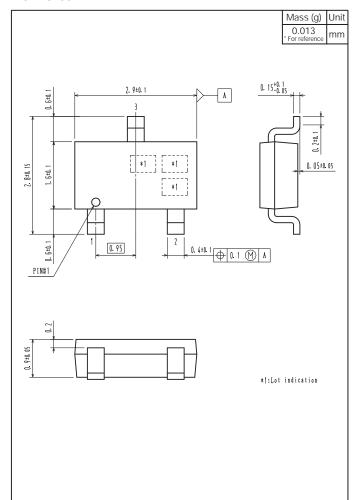
Ambient Temperature, Ta - °C

IT16452

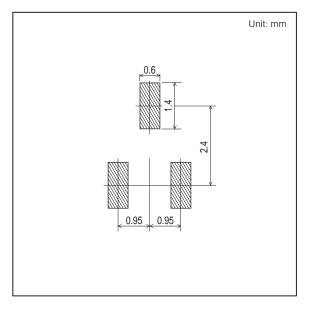


Outline Drawing

CPH3455-TL-H



Land Pattern Example



Note on usage: Since the CPH3455 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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